

### Features, Benefits and Applications

- 1-110 MHz frequency range.
- High frequency stability of  $\pm 20$  PPM,  $\pm 25$  PPM,  $\pm 30$  PPM,  $\pm 50$  PPM
- Typical RMS period jitter of 4 ps
- Typical low current consumption of 8 mA in active mode
- Programmable standby or output enable modes
- Available in four industry standard packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- All-silicon device with outstanding reliability of 2 FIT, 10x improvement over quartz-based devices, enhancing system MTBF
- Outstanding mechanical robustness for portable applications
- Ultra short lead time
- Ideal for consumer electronics, video, graphics card, set top boxes, HDTV, DVR, scanners, printers, copiers, IP camera, etc.
- Ideal for high-speed serial protocols such as: USB 1.1, USB 2.0, SATA, SAS, Fibre Channel, Firewire, Ethernet, PCI Express, etc

### Specifications

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Output Frequency Range	f	1	–	110	MHz	
Frequency Stability	F <sub>stab</sub>	-20	–	+20	PPM	Inclusive of: Initial stability, operating temperature, rated power, supply voltage change, load change, shock and vibration.  <b><math>\pm 20</math> PPM is available for extended commercial temperature only.</b>
		-25	–	+25	PPM	
		-30	–	+30	PPM	
		-50	–	+50	PPM	
Aging	Ag	-1.0	–	1.0	PPM	1st year at 25 °C
Storage Temperature Range		-65	–	+150	°C	
Operating Temperature Range	T <sub>use</sub>	-20	–	+70	°C	Extended Commercial
		-40	–	+85	°C	Industrial
Supply Voltage	V <sub>dd</sub>	1.71	1.8	1.89	V	
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.97	3.3	3.63	V	
Current Consumption	I <sub>dd</sub>	–	6.1	6.7	mA	No load condition, f = 20 MHz, V <sub>dd</sub> = 1.8 V
		–	6.7	7.5	mA	No load condition, f = 20 MHz, V <sub>dd</sub> = 2.5 V, 2.8 V or 3.3 V
Standby Current	I <sub>std</sub>	–	0.4	0.8	μA	$\overline{ST}$ = GND, V <sub>dd</sub> = 1.8 V, Output is Weakly Pulled Down
		–	1.2	2.2	μA	$\overline{ST}$ = GND, V <sub>dd</sub> = 2.5 or 2.8 V, Output is Weakly Pulled Down
		–	2.4	4.3	μA	$\overline{ST}$ = GND, V <sub>dd</sub> = 3.3 V, Output is Weakly Pulled Down
Duty Cycle	DC	45	50	55	%	All V <sub>dds</sub> . f ≤ 75 MHz
		40	50	60	%	All V <sub>dds</sub> . f > 75 MHz
Rise/Fall Time	Tr, Tf	–	1	2	ns	10% - 90% V <sub>dd</sub> =2.5V, 2.8V or 3.3V, 15pf load
		–	1.3	2.5	ns	10% - 90% V <sub>dd</sub> =1.8V, 15pf load
Output Voltage High	VOH	90%	–	–	V <sub>dd</sub>	IOH = -4 mA (V <sub>dd</sub> = 3.3 V) IOH = -3 mA (V <sub>dd</sub> = 2.8 V and V <sub>dd</sub> = 2.5 V) IOH = -2 mA (V <sub>dd</sub> = 1.8 V)
Output Voltage Low	VOL	–	–	10%	V <sub>dd</sub>	IOL = 4 mA (V <sub>dd</sub> = 3.3 V) IOL = 3 mA (V <sub>dd</sub> = 2.8 V and V <sub>dd</sub> = 2.5 V) IOL = 2 mA (V <sub>dd</sub> = 1.8 V)
Output Load	Ld	–	–	15	pF	At maximum frequency and supply voltage. Contact SiTime for higher output load option
Input Voltage High	VIH	70%	–	–	V <sub>dd</sub>	Pin 1, OE or $\overline{ST}$
Input Voltage Low	VIL	–	–	30%	V <sub>dd</sub>	Pin 1, OE or $\overline{ST}$
Startup Time	T <sub>osc</sub>	–	–	10	ms	Measured from the time V <sub>dd</sub> reaches its rated minimum value
Resume Time	T <sub>resume</sub>	–	–	4	ms	Measured from the time ST pin crosses 50% threshold
RMS Period Jitter	T <sub>jitt</sub>	–	–	6.5	ps	f = 75 MHz, V <sub>dd</sub> = 1.8 V
		–	–	4.0	ps	f = 75 MHz, V <sub>dd</sub> = 2.5 V, 2.8 V or 3.3 V
RMS Phase Jitter (random)	T <sub>phj</sub>	–	0.6	–	ps	f = 75 MHz, Integration bandwidth = 900 kHz to 7.5 MHz, V <sub>DD</sub> = 2.5V, 2.8V, or 3.3V
		–	0.8	–	ps	f = 75 MHz, Integration bandwidth = 900 kHz to 7.5 MHz, V <sub>DD</sub> = 1.8V

**■ Specifications (cont.)****Absolute Maximum Ratings**

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

**Absolute Maximum Table**

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	+3.65	V
Electrostatic Discharge	—	6000	V
Theta JA ( with copper plane on VDD and GND)	—	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	—	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)	—	260	°C
Number of Program Writes	—	1	NA
Program Retention over -40 to 125 °C, Process, VDD (0 to 3.65V)	—	1,000+	years

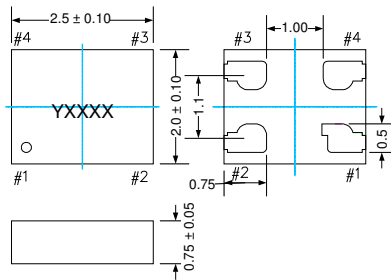
**Environmental Compliance**

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260 °C

### ■ Dimensions, Pin Description and Land Pattern

#### Dimensions (Unit: mm)<sup>[1]</sup>

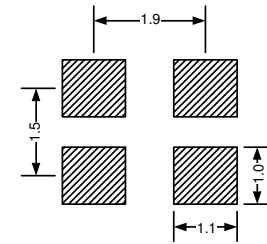
##### 2.5 x 2.0 x 0.75 mm



Pin #1 Functionality	
OE	
H or Open <sup>[3]</sup> ; specified frequency output	
L: output is high impedance	
ST	
H or Open; specified frequency output	
L: output is low level (weak pull down)	

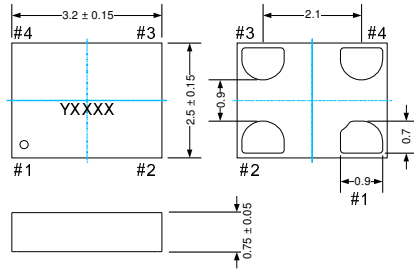
Pin Map	
Pin	Connection
1	OE/ST
2	GND
3	CLK
4	VDD

#### Recommended Land Pattern (Unit: mm)<sup>[2]</sup>



#### Dimensions (Unit: mm)<sup>[1]</sup>

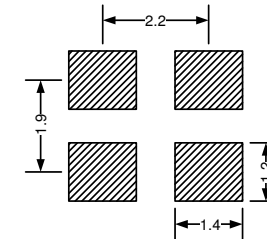
##### 3.2 x 2.5 x 0.75 mm



Pin #1 Functionality	
OE	
H or Open <sup>[3]</sup> ; specified frequency output	
L: output is high impedance	
ST	
H or Open; specified frequency output	
L: output is low level (weak pull down)	

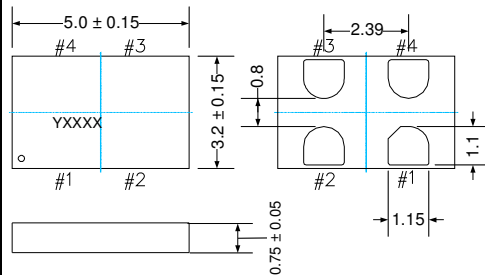
Pin Map	
Pin	Connection
1	OE/ST
2	GND
3	CLK
4	VDD

#### Recommended Land Pattern (Unit: mm)<sup>[2]</sup>



#### Dimensions (Unit: mm)<sup>[1]</sup>

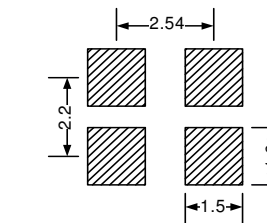
##### 5.0 x 3.2 x 0.75 mm



Pin #1 Functionality	
OE	
H or Open <sup>[3]</sup> ; specified frequency output	
L: output is high impedance	
ST	
H or Open; specified frequency output	
L: output is low level (weak pull down)	

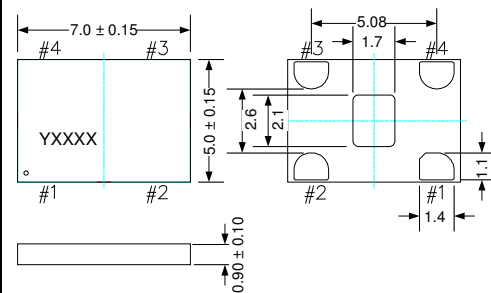
Pin Map	
Pin	Connection
1	OE/ST
2	GND
3	CLK
4	VDD

#### Recommended Land Pattern (Unit: mm)<sup>[2]</sup>



#### Dimensions (Unit: mm)<sup>[1]</sup>

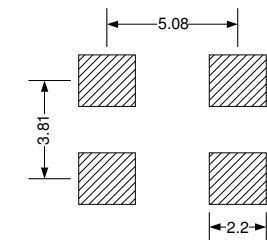
##### 7.0 x 5.0 x 0.90 mm



Pin #1 Functionality	
OE	
H or Open <sup>[3]</sup> ; specified frequency output	
L: output is high impedance	
ST	
H or Open; specified frequency output	
L: output is low level (weak pull down)	

Pin Map	
Pin	Connection
1	OE/ST
2	GND
3	CLK
4	VDD

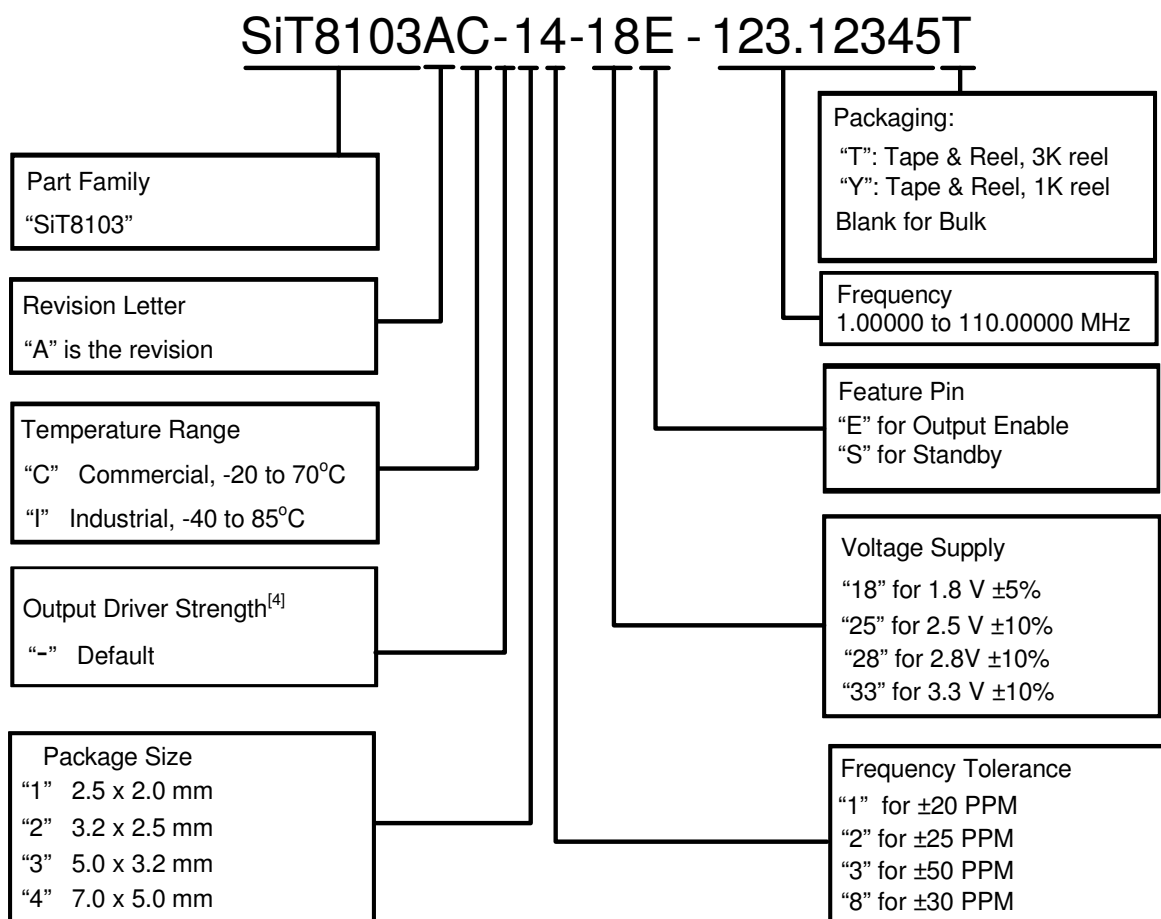
#### Recommended Land Pattern (Unit: mm)<sup>[2]</sup>



#### Notes:

1. Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
2. A capacitor of value 0.1 μF between Vdd and GND is recommended.
3. In 1.8V mode, a resistor of <100 kΩ between OE pin and VDD is recommended.

■ Part No. Guide- How to Order



**Note:**

4. Contact SiTime for different drive strength options for driving higher loads or reducing EMI.

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